

RZ/G3S

R01AN7182EJ0110

Rev.1.10

Thermal Management Guideline

Feb. 19, 2025

Information

The calculation results of power consumption, limit T_a , and θ_{ja} are shown after the next page for reference.

Target Device

RZ/G3S

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1. Specification of Junction Temperature

The specification of T_j (junction temperature) is defined as follows.

Users have to use this device without violating the following specification.

- Operating temperature

$$-40^{\circ}\text{C} \leq T_{j\text{max}} \text{ (maximum temperature at junction side)} \leq 125^{\circ}\text{C}$$

The calculation method of T_{jmax} is shown in **Section 3, Calculation Method of T_{jmax}**.

Check T_{jmax} according to this calculation method.

2. Definition of Each Characteristic

- The temperature at the center of the package surface is defined as Tt-center.

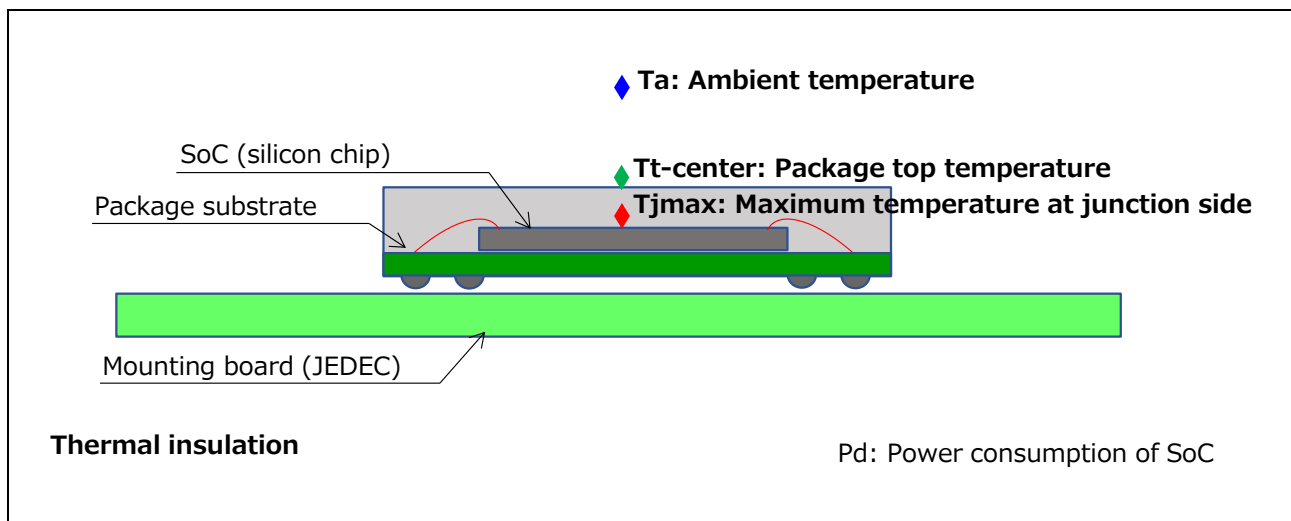


Figure 2.1 Definition of Each Characteristic

$$\theta_{ja} \text{ (thermal resistance between } T_j \text{ and } T_a) = \frac{T_{jmax} - T_a}{P_d}$$

$$\Psi_{jt} \text{ (at Package center)} = \frac{T_{jmax} - T_{t-center}}{P_d}$$

3. Calculation Method of Tjmax

- After measuring Pd (power consumption of Soc) and T_{t-center} in your environment, calculate Tjmax using the next formula.
- Check that “Tjmax” which you calculated is within the specification.

$$T_{jmax}(^{\circ}\text{C}) = T_{t\text{-center}}(^{\circ}\text{C}) + \Psi_{jt}(\text{at Package center})(^{\circ}\text{C}/\text{W})^{(*1)} \times P_d(\text{W})$$

Note 1. Refer to the table below for Ψ_{jt} (at chip center).

Ψ_{jt} (at chip center) is the value calculated by thermal simulations.

Refer to **Section 5, Thermal Simulation Model** about the thermal simulation model.

Note that Ψ_{jt} is limited to the open top case.

Table 3.1 Ψ_{jt} (at Package Center) of 14mm sq and 13mm sq

Package Outline	Heat Sink	Ψ_{jt} (at Package Center)($^{\circ}\text{C}/\text{W}$)
14mm sq	No	0.56
13mm sq	No	0.55

4. Reference Information

4.1 Reference Information

- The calculation results of power consumption are shown after the next page for reference.
- Check the limit Ta of your use case. The limit Ta was calculated from thermal simulation results.

4.2 Operation Summary in Use Case

Table 4.1 lists the details of the conditions in use case 1.

- Power consumption estimation conditions

Tj = 125°C, Power supply (VDD, VDD_ISO, PLLx_AVDD) = 0.94 V, Power supply (DDR_VDDQ) = 1.1 V,
Power supply (PVDD18, DDR_VAA, USB_AVDD18) = 1.8 V,
Power supply (PVDD33, USB_VDD33, XSPI_PVDD, SD0_PVDD, SD1_PVDD, PVDD182533_0,
PVDD182533_1) = 3.3 V, Process = FF process silicon, CPU: Cortex-A55 at 1.1 GHz, LPDDR4-1600 16 bits × 1ch

Table 4.1 Operation Summary of Use Case 1

Use Case	Operation Summary
Use case 1	Use case assuming the below conditions <ul style="list-style-type: none"> • CPU (1 core (CPU0)): use rate 62% • System/Bus/Clock: use rate 53% • USB2.0: use rate 0% • Gbit Ethernet: use rate 30% • DRAM: use rate 28%

4.3 Power Consumption in Use Case

Table 4.2 lists a calculated estimation of power consumption in use case 1.

Table 4.2 Power Consumption in Use Case 1

					Unit: (W)
Use Case	0.94 V	1.1 V	1.8 V	3.3 V	Total
Use case 1	1.99	0.10	0.02	0.47	2.59

4.4 Limit Ta in Each Use Case (14mm sq)

We calculated the limit Ta*¹ from θ_{ja} , which is calculated by thermal simulation.

The limit Ta is shown in the following table. However, note that the limit Ta and θ_{ja} in each use case is a reference value based on JEDEC environment, and Ta and θ_{ja} could be fluctuated by the customer use case.

The formula for the limit Ta is as follows.

Note 1. The limit Ta is the limit value of Ta to keep Tjmax within the specified value.

Formula: Limit Ta(°C) = 125(°C) – Pd × θ_{ja}

Table 4.3 Limit Ta in Each Use Case (14mm sq)

Unit: (°C)

Use Case	w/o Heat Sink			w/ Heat Sink (60 mm□)+adhesive		
	Air Velocity 0m/sec	Air Velocity 1m/sec	Air Velocity 2m/sec	Air Velocity 2m/sec *TIM 1W/mK	Air Velocity 2m/sec *TIM 3W/mK	Air Velocity 2m/sec *TIM 6W/mK
Use case 1	67.2	76.0	78.4	94.4	97.8	98.8

*TIM: Thermal Interface Material. This acts as an adhesive between the heat sink and the RZ/G3S.

θ_{ja} will be as follows.

Refer to **Section 5, Thermal Simulation Model** for the thermal simulation model.

Table 4.4 θ_{ja} in Each Use Case (14mm sq)

Unit: (°C/W)

Use Case	w/o Heat Sink			w/ Heat Sink (60 mm□)+adhesive		
	Air Velocity 0m/sec	Air Velocity 1m/sec	Air Velocity 2m/sec	Air Velocity 2m/sec *TIM 1W/mK	Air Velocity 2m/sec *TIM 3W/mK	Air Velocity 2m/sec *TIM 6W/mK
Use case 1	22.3	18.9	18.0	11.8	10.5	10.1

*TIM: Thermal Interface Material. This acts as an adhesive between the heat sink and the RZ/G3S.

4.5 Limit Ta in Each Use Case (13mm sq)

We calculated the limit Ta*¹ from θ_{ja} , which is calculated by thermal simulation.

The limit Ta is shown in the following table. However, note that the limit Ta and θ_{ja} in each use case is a reference value based on JEDEC environment, and Ta and θ_{ja} could be fluctuated by the customer use case.

The formula for the limit Ta is as follows.

Note 1. The limit Ta is the limit value of Ta to keep Tjmax within the specified value.

Formula: Limit Ta(°C) = 125(°C) – Pd × θ_{ja}

Table 4.5 Limit Ta in Each Use Case (13mm sq)

Unit: (°C)

Use Case	w/o Heat Sink			w/ Heat Sink (60 mm□)+adhesive		
	Air Velocity 0m/sec	Air Velocity 1m/sec	Air Velocity 2m/sec	Air Velocity 2m/sec *TIM 1W/mK	Air Velocity 2m/sec *TIM 3W/mK	Air Velocity 2m/sec *TIM 6W/mK
Use case 1	67.2	76.0	78.4	94.4	97.8	98.8

*TIM: Thermal Interface Material. This acts as an adhesive between the heat sink and the RZ/G3S.

θ_{ja} will be as follows.

Refer to **Section 5, Thermal Simulation Model** for the thermal simulation model.

Table 4.6 θ_{ja} in Each Use Case (13mm sq)

Unit: (°C/W)

Use Case	w/o Heat Sink			w/ Heat Sink (60 mm□)+adhesive		
	Air Velocity 0m/sec	Air Velocity 1m/sec	Air Velocity 2m/sec	Air Velocity 2m/sec *TIM 1W/mK	Air Velocity 2m/sec *TIM 3W/mK	Air Velocity 2m/sec *TIM 6W/mK
Use case 1	22.3	18.9	18.0	11.8	10.5	10.1

*TIM: Thermal Interface Material. This acts as an adhesive between the heat sink and the RZ/G3S.

5. Thermal Simulation Model

5.1 Ref: SIMULATION Model for Thermal Analysis

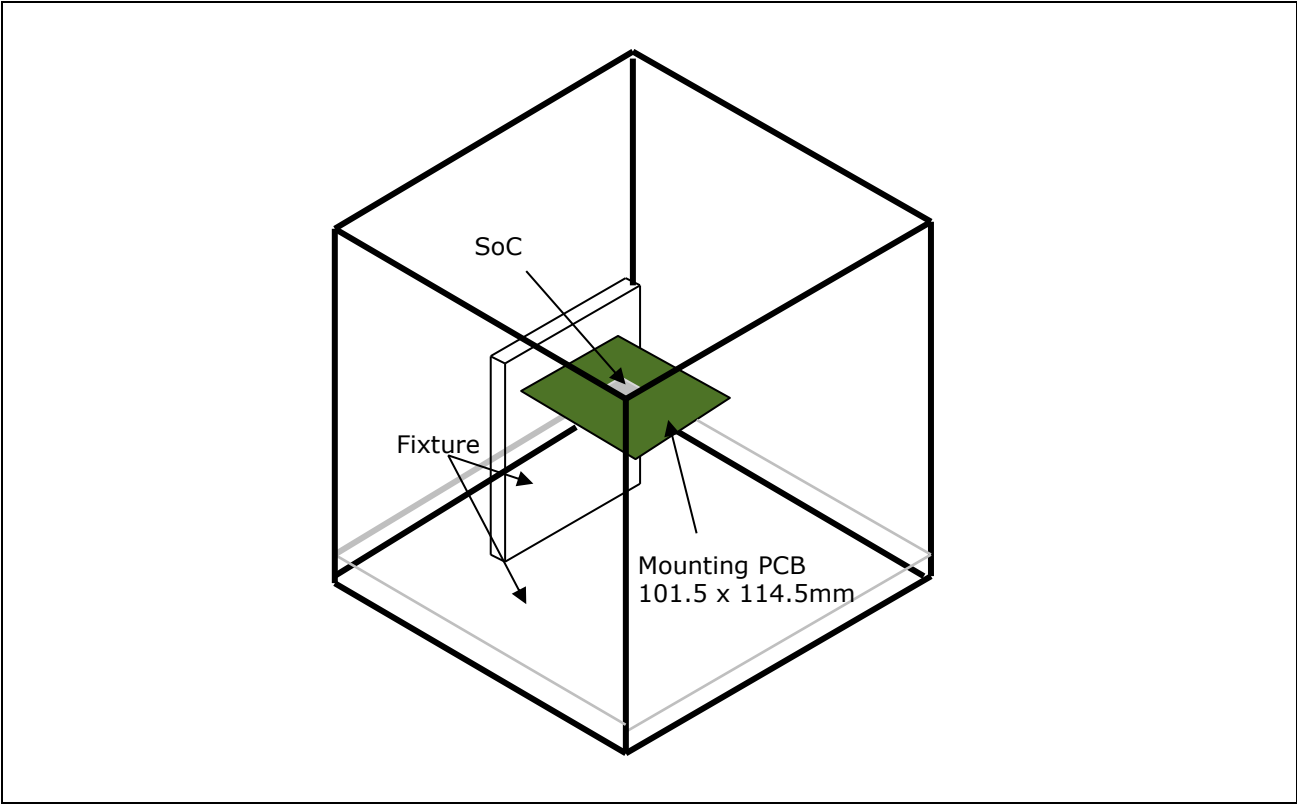


Figure 5.1 external environment

L1	SR	0.032	[mm]
	Cu 50%	0.07	[mm]
L2	FR4	0.375	[mm]
	Cu 95%	0.035	[mm]
L3	FR4	0.64	[mm]
	Cu 95%	0.035	[mm]
L4	FR4	0.375	[mm]
	Cu 50%	0.07	[mm]
SR		0.032	[mm]
Total		1.664	[mm]

Figure 5.2 Mounting PCB Layer Information

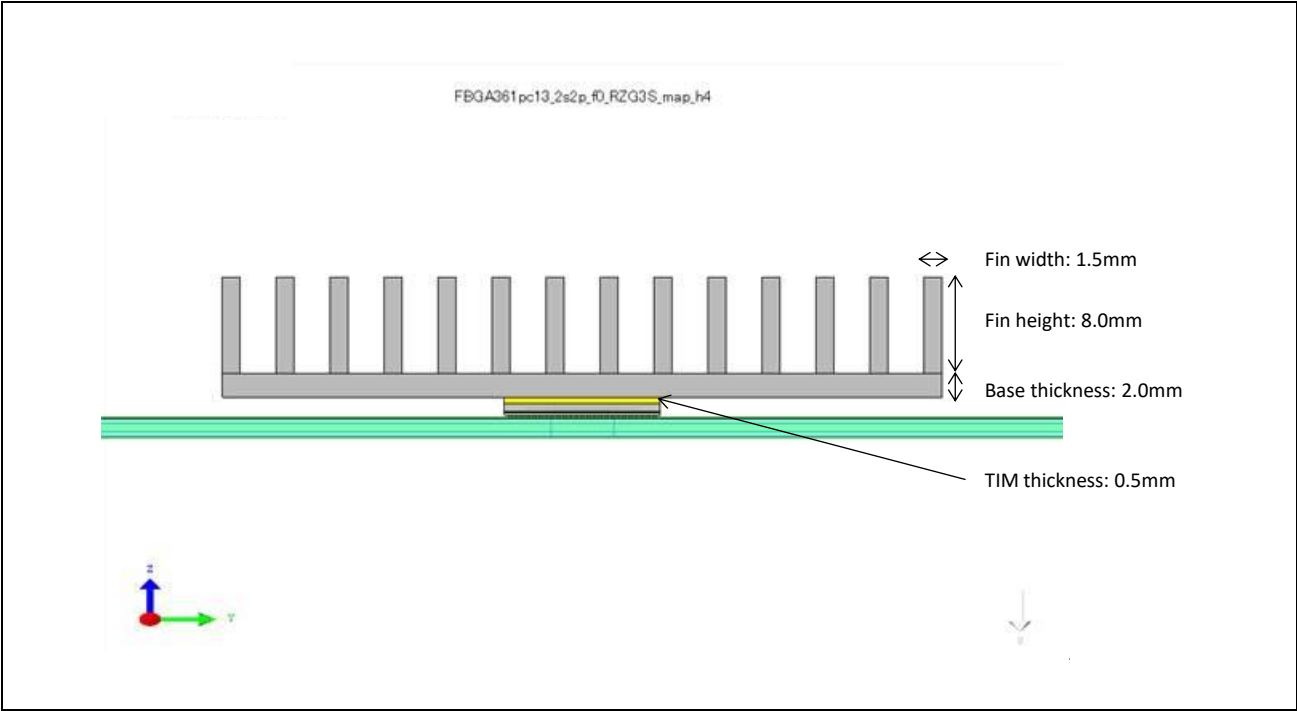


Figure 5.3 60mm sq Heat Sink Information

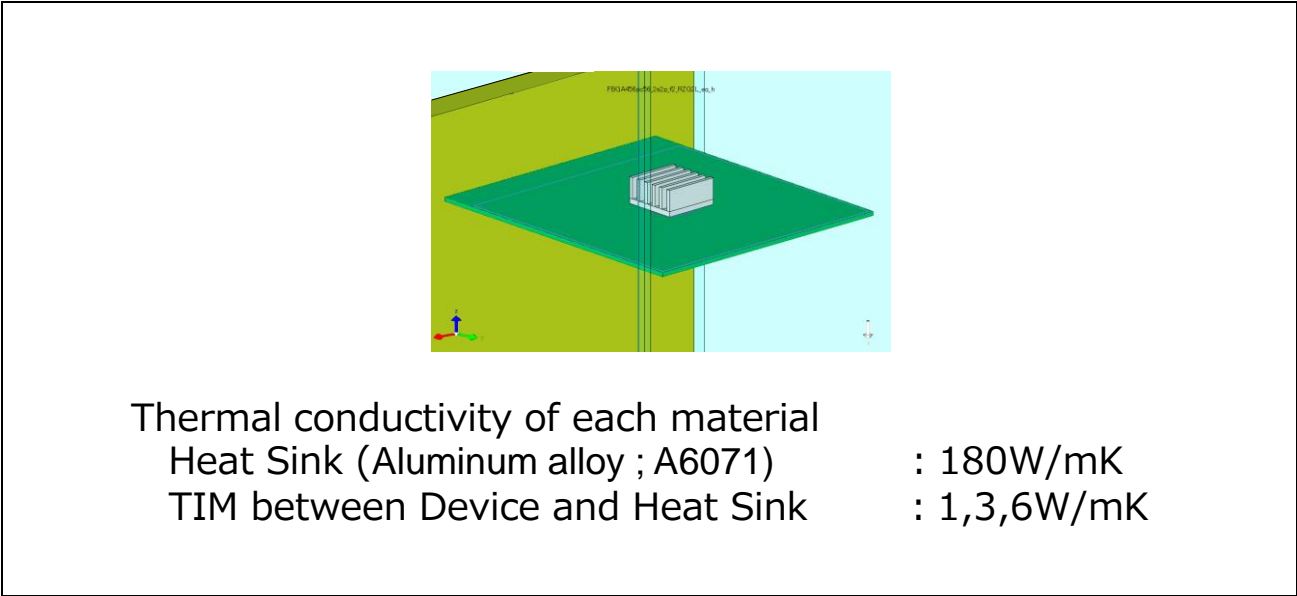


Figure 5.4 Thermal Conductivity of Each Material

5.2 Ref: Parameter (θ_{jc} , θ_{jb})

Table 5.1 Parameter (θ_{jc} , θ_{jb}) of 14mm sq and 13mm sq

Package Outline	Heat Sink	θ_{jc} (°C/W)	θ_{jb} (°C/W)
14mm sq	No	10.2	13.2
13mm sq	No	10.1	13.4

REVISION HISTORY		RZ/G3S Thermal Management Guideline	
Rev.	Date	Description	
		Page	Summary
1.00	Dec. 11, 2023	—	First edition issued
1.10	Feb. 19, 2025	1	Information: The description, modified
		6 to 8	4. Reference Information: Use case 2, deleted
		6	The descriptions in sections 4.1, 4.2, and 4.3, modified
		6	Table 4.1, modified
		6 to 8	The values in tables 4.2, 4.3, and 4.5, modified

General Precautions in the Handling of Microprocessing Unit and Microcontroller Unit Products

The following usage notes are applicable to all Microprocessing unit and Microcontroller unit products from Renesas. For detailed usage notes on the products covered by this document, refer to the relevant sections of the document as well as any technical updates that have been issued for the products.

1. Precaution against Electrostatic Discharge (ESD)

A strong electrical field, when exposed to a CMOS device, can cause destruction of the gate oxide and ultimately degrade the device operation. Steps must be taken to stop the generation of static electricity as much as possible, and quickly dissipate it when it occurs. Environmental control must be adequate. When it is dry, a humidifier should be used. This is recommended to avoid using insulators that can easily build up static electricity. Semiconductor devices must be stored and transported in an anti-static container, static shielding bag or conductive material. All test and measurement tools including work benches and floors must be grounded. The operator must also be grounded using a wrist strap. Semiconductor devices must not be touched with bare hands. Similar precautions must be taken for printed circuit boards with mounted semiconductor devices.

2. Processing at power-on

The state of the product is undefined at the time when power is supplied. The states of internal circuits in the LSI are indeterminate and the states of register settings and pins are undefined at the time when power is supplied. In a finished product where the reset signal is applied to the external reset pin, the states of pins are not guaranteed from the time when power is supplied until the reset process is completed. In a similar way, the states of pins in a product that is reset by an on-chip power-on reset function are not guaranteed from the time when power is supplied until the power reaches the level at which resetting is specified.

3. Input of signal during power-off state

Do not input signals or an I/O pull-up power supply while the device is powered off. The current injection that results from input of such a signal or I/O pull-up power supply may cause malfunction and the abnormal current that passes in the device at this time may cause degradation of internal elements. Follow the guideline for input signal during power-off state as described in your product documentation.

4. Handling of unused pins

Handle unused pins in accordance with the directions given under handling of unused pins in the manual. The input pins of CMOS products are generally in the high-impedance state. In operation with an unused pin in the open-circuit state, extra electromagnetic noise is induced in the vicinity of the LSI, an associated shoot-through current flows internally, and malfunctions occur due to the false recognition of the pin state as an input signal become possible.

5. Clock signals

After applying a reset, only release the reset line after the operating clock signal becomes stable. When switching the clock signal during program execution, wait until the target clock signal is stabilized. When the clock signal is generated with an external resonator or from an external oscillator during a reset, ensure that the reset line is only released after full stabilization of the clock signal. Additionally, when switching to a clock signal produced with an external resonator or by an external oscillator while program execution is in progress, wait until the target clock signal is stable.

6. Voltage application waveform at input pin

Waveform distortion due to input noise or a reflected wave may cause malfunction. If the input of the CMOS device stays in the area between V_{IL} (Max.) and V_{IH} (Min.) due to noise, for example, the device may malfunction. Take care to prevent chattering noise from entering the device when the input level is fixed, and also in the transition period when the input level passes through the area between V_{IL} (Max.) and V_{IH} (Min.).

7. Prohibition of access to reserved addresses

Access to reserved addresses is prohibited. The reserved addresses are provided for possible future expansion of functions. Do not access these addresses as the correct operation of the LSI is not guaranteed.

8. Differences between products

Before changing from one product to another, for example to a product with a different part number, confirm that the change will not lead to problems. The characteristics of a microprocessing unit or microcontroller unit products in the same group but having a different part number might differ in terms of internal memory capacity, layout pattern, and other factors, which can affect the ranges of electrical characteristics, such as characteristic values, operating margins, immunity to noise, and amount of radiated noise. When changing to a product with a different part number, implement a system-evaluation test for the given product.

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